Gas Contrasting of Multiphase and Composite Materials

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GAS CONTRASTING OF MULTIPHASE AND COMPOSITE MATERIALS

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Summary

The contrast between various constituents of multiphase materials is the most important factor for quantitative microstructural analysis. How to achieve it by gas contrasting is the subject of the present report, which starts in its first part with the description of the gas-contrasting chambers and the technique of gas contrasting, continues with the demonstrating and explanation of gas-contrasted metal, composite, and ceramic microstructures, and finishes with the interpretation of the gas-contrasting effect on the basis of the theory of thin interference layers.

In the second part the structure of an HfC-Co hard metals was gascontrasted for the purpose of quantitative microstructural analysis. Interference coatings were formed on the structural components in the process. These produce the desired colour contrast. Their structure is investigated using auger electron spectroscopy. It was found that, independent of the cathode material used, the coating overall contains mainly oxygen and the cathode element, that the oxygen concentration beyond a certain depth in the coating assumes approximately the value of uncoated specimen, that below this depth in the coating the cathode material can no longer be identified and that above this depth in the coating no hafnium or carbon is detectable on the HfC-phase while cobalt is present in the coating structure in the Co-phase.
It is essential to the qualitative and quantitative microscopic analysis of a material's microstructure that its constituents be distinguishable. Distinctions between the phases, crystallites, and boundaries of the polished section are based on their differential interaction behavior—reflection and absorption—with optical light rays in optical microscopy or with electron beams in electron microscopy. To obtain an image that can be analyzed microscopically—i.e., which is rich in contrast—these differences in the reflection or absorption behavior of the microstructural constituents must be "intensified." The relevant methods of preparation are classed under the term, contrasting. Especially in quantitative microstructural analysis, as schematically summarized in Fig. 5-1 this contrasting step is of particular importance.

The microstructural constituents in the microscopic image can be differentiated either by a bright/dark contrast or by a color contrast. The bright/dark contrast is based on intensity differences of the light waves (amplitude condition); the color contrast, on differences in wavelength (phase condition). Methods of contrasting are based either on the formation or removal of surface layers or on the simple use of optical aids. The use of optical aids (polarized, brightfield and darkground illumination, filters, etc.) is restricted, however, to certain properties of the specimens (e.g., polarizability of phases), but it has the advantage of keeping the surface of the specimen unchanged.¹²

The removal of surface layers—as, for example, by cathodic ion etching⁴—changes the polished surface but may bring out an even more "true image" of the microstructure, since deformed surface parts disappear. On the

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Fig. 5-1. Elements of Quantitative Microstructural Analysis (QMA).
other hand, however, the contrasting effect remains restricted. This is the reason why layer formation is usually the most effective way to contrast. Contrasting layers are produced either by vapor phase deposition, where practically no interaction occurs between the layer and the sample surface, or by chemical or electrochemical etching. In the latter case, interaction between the etching agent and the polished section surface takes place. Gas contrasting, as described in the next section, belongs to the layer forming methods.

**THE GAS-CONTRASTING APPARATUS**

Gas contrasting takes place in a vacuum chamber that is externally similar to a hot stage attached to the mechanical stage of a microscope. The working principle is illustrated in Fig. 5-2; the chamber, in Fig. 5-3 (see color insert). The sample is handled in one of three ways:

1. It is connected separately between two electrodes (cathode, anode).
2. It serves itself as anode if it is a conducting material.
3. It is directly fixed on the adjustable anode, which can be swiveled and therefore alternatively moved into the position opposite the cathode or below the microscope objective (see Fig. 5-2). Doing so permits the contrasting process to be controlled directly by tilting the specimen below the microscope objective for *in-situ* observation.

The gas-contrasting chamber prototype (Fig. 5-3) takes normal-sized, mounted metallographic specimens (~25 mm in diameter). Its airtightness is increased by the pneumatic tilting device because the latter is operated by the same gas used for etching. Figure 5-2 illustrates its mode of operation. In the upper diagram, two needle valves (1 and 2) are shut and one (3) is open. This disposition sets up an excess pressure in the cylinder that moves the piston and lever system. The specimen is pneumatically tilted under the objective and automatically seated by resting against the cover glass. The piston stroke and,
hence, the specimen height (11 to 15 mm) and diameter (< 27 mm) can be varied by means of adjusting screws. If the position of the valves is altered to correspond with the lower diagram in Fig. 5-2, the piston falls. Since the specimen with its holder is attached to the piston eccentrically through a ball joint, it tilts back under its own weight into a vertical position opposite the cathode.

THE PRINCIPLE OF GAS CONTRASTING

After the pumping unit connected to the pump nozzle is used to evacuate the gas-contrasting chamber, as shown in Fig. 5-2, it is filled via the needle valves with the etching gas or gas mixture. The ignited electron beam between the electrodes may be focussed by direct observation because the chamber (see Fig. 5-3) is transparent (it is made of quartz glass); the focussing additionally prevents discharging of the beam to chamber parts if they are nonconducting and different from the anode (quartz).

While the etching gas is being ionized by the electron beam, elements of the cathode material evaporate and mix into the gaseous etchant. The degree of ionization and evaporation—and with them, indirectly, the duration of contrasting—depends on the variable electrical data of current intensity and potential as well as on the distance between the sample anode and cathode and the gas pressure. The gaseous ions may be produced either by accumulation of electrons on the neutral gas molecules—that is, by surface ionization (negative ions)—or by impact ionization when accelerated electrons transfer their kinetic energy to neutral gas molecules via impact processes. In the latter case, positive ions are formed that are accelerated in the electrical field. They hit the cathode, causing sputtering of the cathode material. The result is a mixture of atoms and/or ions of the etching gas and the cathode material; the mixture sublimates on the specimen’s surface and forms interference layers that color different microstructural constituents differently. This effect is well known.

Basically, no restriction exists with respect to various groups of materials for this type of layer formation. It takes place on the surfaces of the following:

1. Metallic materials, including intermetallic compounds
2. Composites, including hard metals
3. Ceramic materials, including glasses

The interaction tendency between the various materials and the etching gas is different, however, and this is why layer formation occurs in one of the following ways:

1. By interaction (reaction, solid solution) between the gaseous etchant and the material’s constituents on the specimen’s surface ("interaction layers")
2. By adsorption or sublimation of the gas atoms, ions, or molecules onto the material’s constituents on the specimen’s surface without interaction ("adsorption layers")

If the layer formation is based on interaction, it is controlled by the free energies of reaction or solution and their temperature dependencies, and these differ for the various microstructural constituents. In this case, differences in chemical composition and X-ray structure and differences in layer growth rate on the different microstructural constituents have to be taken into account. Interactions promote temperature increases in gas contrasting (Fig. 5-4).

If the specimen is not directly connected to the anode, sublimation might be especially favored because heating of the specimen will not then occur, thereby promoting adsorption layer formation. Adsorption layers for all microstructural constituents should have approximately identical chemical composition, structure, and thickness because their growth rate is constant across the specimen surface.
A study of gas-contrasted HfC-Co hard-metal microstructures using Auger electron spectroscopy recently demonstrated the following:

1. A layer grows on the original, uncoated surface ("grown zone") that is predominantly formed by the elements of the gaseous etchant (etching gas and evaporated atoms from the cathode material).
2. Elements of the original specimen material may migrate into the growing layer, but this depends on the type of constituent.
3. Elements of the etching gas penetrate the interface between the layer and the original, uncoated surface, thereby altering its nature at least slightly ("diffusion zone").

Subsequently, a layer formed by gas contrasting is subdivided into, and is inhomogeneous within, two zones—a grown zone and a diffusion zone. The layer may be composed differently on different phases or constituents.

These results are summarized graphically and schematically in Fig. 5-5. Similar information about an inhomogeneous and nonstoichiometric layer structure was formerly obtained by Auger analysis of layers after chemical etching.

**GAS-CONTRASTED MICROSTRUCTURES**

In order to get a more general assessment about gas contrasting, experiments have been performed with various classes of materials, as follows:
1. Single and multiphase metals, including intermetallic compounds
2. Composites, including hard metals
3. Ceramic materials

The microstructures of some of these have been selected to serve as examples. Others are shown in the quoted literature.

During the experiment for contrasting the polished structure of an austenitic steel by means of oxygen ions, a certain color sequence occurred with increasing contrasting time. An improvement of the original contrast between crystallites and grain boundaries produced by chemical etching did not occur.

The same phenomenon occurs in the example shown in Fig. 5-6 of a two-phase infiltrated alloy of copper and tungsten. Figure 5-6(a) shows the polished microstructure as it appeared under the microscope. Chemical etching (10-percent aqueous ammonium-persulphate solution) leads to a negligible increase in the contrast differentiation between the two phases [Fig. 5-6(b)], which, however, is not comparable with the color contrast obtained by means of gas contrasting in oxygen [Figs. 5-6(c) and (d)]. In addition, this color contrast can be controlled with the contrasting duration. It is true that the same characteristic color sequence as in steel is produced for both phases, but the same color sequence occurs in copper after a different contrasting duration than that for tungsten. The color sequence is also present at the oxide inclusions [Figs. 5-6(c) and (d), blue]. (See color insert for Figs. 5-6 through 5-11.)

Differentiation of the phases is considerably improved by means of gas contrasting, but grain boundaries or crystallites do not become visible. Figure 5-7 shows intermetallic phases of uranium and silicon (U₃Si₂, U₃Si) together in one microstructure, where U₃Si is the matrix phase and U₃Si₂ are the discrete second-phase particles. As made clear by Fig. 5-7, gas contrasting provides definite contrast distinction between the phases. The bright and dark contrast distinction required for quantitative microstructural analysis may be easily obtained by use of color filters. All phases again traverse (after differential contrasting time) the characteristic color sequence as in the other examples, finally entering an achromatic state that is no longer subject to change.

Hard metals form an important group among composites, for which gas contrasting usually provides satisfying contrast. Figure 5-8 illustrates the microstructure of HfC-Co hard metal, which was the subject for the investigation of the layer structure (see Fig. 5-5). As demonstrated in Fig. 5-9, both phases—the metal binder as well as the carbide phase—traverse the characteristic color sequence but shift mutually in time. This statement also holds true for oxide cermets (Fig. 5-10) as well as single-phase ceramics (Fig. 5-11), where the complete color sequence occurs slower than it does in metals. The results of these experiments can be summarized as follows:

1. Gas contrasting produces a characteristic color sequence with increasing contrasting duration, and this is independent of the material, the structure, the type of gas, and other contrasting conditions.
2. The colors assumed by the various phases or constituents of a microstructure after a certain duration of contrasting under otherwise identical conditions differ; i.e., the relative speed with which the various constituents traverse the characteristic color sequence depends on the material.
3. For "two-dimensional" features, such as grain or phase boundaries, gas contrasting does not provide contrast improvement.
4. The absolute speed of sequence of the colors depends on the etching conditions such as the type and pressure of gas, intensity and potential of current, and distance between electrodes.
5. The color sequence always ends in an achromatic, unchangeable state.
6. The relatively different speed of the color sequence in various constituents permits their contrasting through reproducible and controlled color contrast.
7. For the purpose of quantitative microstructural analysis, the color contrast may be converted into bright-dark contrast by using interference filters at the microscope.

The interpretation of the gas-contrasting effect

As mentioned at the beginning of this Chapter, it is a necessary presupposition for the optical differentiation and quantitative microscopical description that sufficient contrast exist between the various constituents of a microstructure. Bright-dark contrast is mathematically defined to be

\[ K = \frac{R_a - R_\beta}{R_a} \]  

where reflectance is defined as the ratio between reflected and incident (original) radiation intensity, and the reflection coefficient, \( r \) (see Eqs. 5-2, 5-3, and 5-4), is defined by the root of the reflectance, \( R(r_a = \sqrt{R_a^\alpha}; r_\beta = \sqrt{R_\beta^\beta}) \). \( R_\alpha \) and \( R_\beta \) are the reflectances of constituents \( \alpha \) and \( \beta \), respectively.

With the limiting condition,

\[ R_\alpha > R_\beta \]

Eq. 5-1 establishes the following:

\[ 0 \leq K \leq 1 \]

Maximum bright-dark contrast is obtained with minimum reflectance of microstructural constituent \( \beta \), or
Taking into account that contrast enhancement by gas contrasting is based on layer formation, the theoretical consideration has to start with the reflectance of the "coated" constituent $\beta$, that is, $R_{\beta S}$, which, according to the Fresnel equation for normal incidence, has the form\textsuperscript{7,25,26,27}

$$R_{\beta S} = \frac{r_0^2 + r_1^2 + 2 r_0 r_1 \cos \Delta \lambda}{1 + r_0^2 r_1^2 + 2 r_0 r_1 \cos \Delta \lambda}$$  \hspace{1cm} (5-2)

where $r_0 (= \sqrt{R_0})$, the reflection coefficient at the interface environment/layer, is defined as follows:

$$r_0 = \frac{(n_S - n_0)^2 + k_S^2}{(n_S + n_0)^2 + k_S^2}$$  \hspace{1cm} (5-3)

and $r_1 (= \sqrt{R_1})$ the reflection coefficient at the interface layer/constituent, as:

$$r_1 = e^{-\frac{2\pi k_0}{\lambda}d_S} \frac{(n_0 - n_S)^2 + (k_0 - k_S)^2}{(n_S + n_0)^2 + (k_0 + k_S)^2}$$  \hspace{1cm} (5-4)

and the optical phase shift between incident and reflected beam, $\Delta \lambda$, as:

$$\Delta \lambda = \left(\frac{4\pi n_S}{\lambda}\right)d_S + \delta_{0S} - \delta_{8S}$$  \hspace{1cm} (5-5)

In Eqs. 5-3, 5-4, and 5-5,

- $n_0$, $n_S$, $n_\beta$ = refractive index of environment (O), layer (S), and constituent (\beta), respectively
- $k_0$, $k_S$, $k_\beta$ = absorption coefficient of environment (O), layer (S), and constituent (\beta), respectively
- $\lambda$ = wavelength of optical beam
- $d_S$ = layer thickness on constituent $\beta$ of microstructure

The first term, $\left(\frac{4\pi n_S}{\lambda}\right)d_S$, in Eq. 5-5 refers to the optical path difference between the incident and reflected light ray transformed into arc units, $\frac{2\pi}{\lambda}$, that results from the optical path through the interface layer, $2n_Sd_S$, whereas the second, $\delta_{0S}$, and the third, $\delta_{8S}$, terms describe the optical phase shiftings as transient conditions for the reflections at the interfaces of environment/layer and layer/constituent, respectively\textsuperscript{25}

In air or vacuum ($n_0 = 1$); transmissive, nonabsorbing layers [$n_0 < n_S < n_\beta$; $k_S = 0$; $r \neq f (d_S, \lambda)$]; and almost nonabsorbing microstructural constituents ($k_\beta = 0$),\textsuperscript{26} the optical phase shifts become

$$\delta_{0S} = \pi$$  \hspace{1cm} (5-6)
$$\delta_{8S} = \pi$$  \hspace{1cm} (5-7)

and Eq. 5-5 becomes

$$\Delta \lambda = \left(\frac{4\pi n_S}{\lambda}\right)d_S + \pi - \pi$$  \hspace{1cm} (5-8)

Additionally, we observe that extinction interference on constituent $\beta$ occurs if the optical phase shift for the beam becomes

$$\Delta \lambda = (2m + 1)\pi$$  \hspace{1cm} (5-9)

where $m = 0, 1, 2, \ldots$

From Eq. 5-2, one obtains

$$R_{\min} = \left[\frac{r_0 - r_1}{1 - r_0 r_1}\right]^2$$  \hspace{1cm} (5-9)

and from Eq. 5-7,

$$d_S = \frac{(2m + 1)\lambda}{4n_S}$$  \hspace{1cm} (5-10)

Equation 5-10 is the well-known condition for optical interference extinction. Both Eqs. 5-9 and 5-10 provide the crucial basis for interpreting gas contrasting; that is, maximum bright-dark contrast is either (1) due to the fitting of the optical constants of the layer ($n_S$ and $k_S$) and of the microstructural constituent $\beta$ ($n_\beta$ and $k_\beta$) in such a way that for nonabsorbing layers and independently of layer thickness, Eq. 5-9 results in the value, $R_{\min} = 0$; or (2) takes place independently of the optical constants of the microstructural constituent $\beta$ and with a definite layer thickness, $d_S$, on this constituent, in which case, with monochromatic light, $\lambda$, and given refraction index $n_S$, of the nonabsorbing layer material, Eq. 5-10 is fulfilled.

Microscopical microstructural analyses are usually made with white light, which is not monochromatic. Although differently reflected from various "uncoated" microstructural constituents, white light does not provide sufficient contrast [Fig. 5-12(a)]. After layer formation, however, a defined spectral color will suffer extinction by reflection according to Eq. 5-9 or 5-10; the color is different for different constituents. The rest of the spectral colors mix, resulting in nonwhite complementary colors, obviously different for the various constituents and therefore providing color contrast [Figs. 5-12(b) and (c)].
First, assuming that the growing layer on the various microstructural constituents achieves equal thickness whether or not identical structure [Fig. 5-12(b)], contrast—including color contrast—may occur as a result of the different interaction between the optical constants of the constituents and those of the layer (Eq. 5-9).

Second, assuming that the growing layer on the various microstructural constituents achieves identical or non-identical structure but unequal thickness [Fig. 5-12(c)], contrast and color contrast follow from Eq. 5-10 even when the role of the optical constants of the constituents is neglected. (See color insert for Fig. 5-12.)

The existing results are inadequate to determine which mechanism controls gas contrasting or to what extent different mechanisms take part in it. To explain the gas-contrasting effect using an engineering approach, the following consideration must be restricted to a model with different layer thicknesses. This simplification does not state that the effect of the optical constants of the various microstructural constituents on contrasting may be generally neglected. In Fig. 5-13, a gas-contrasted specimen is imagined to be covered by nonabsorbing, transmissive layers of different thicknesses on different constituents. The light rays (1 and 2) coming from the objective are partially reflected from (1' and 2') and partially transmitted through the layer. The ray penetrating the layer changes its direction corresponding to the refractive index \( n_s \) of the layer. Ray 1, for example, is reflected again at the interface layer/constituent \( \beta \) and returns in the form of ray 1" to the environment. There it interferes with the primarily reflected part 2' of the original ray 2. Extinction occurs under the following condition:

\[
d_s = \frac{(2m + 1)\lambda}{4 \sqrt{n_s^2 - \sin^2 \phi}}
\]  

This equation leads to Eq. 5-10 in the case of normal beam incidence \( (\phi = 0) \). If the etched specimens are observed in white light, spectral colors satisfying the conditions in Eqs. 5-1 or 5-2 will suffer extinction. The remaining colors are superimposed to produce complementary or mixed colors. Since layer thickness is continually increasing during gas contrasting, it reaches the value \( (480/2 \text{ nm}) \) at which extinction occurs for the blue component of white light first. The corresponding complementary color can be obtained from the color triangle in Fig. 5-14 by drawing a straight line from the wavelength that has suffered extinction through the white point (W). The intersection of this straight line with the opposing side of the triangle gives the wavelength of the mixed color, which can then be compared on the color ring. If, for example, blue suffers extinction, the complementary color, yellow, is obtained. The white point for daylight (E) is displaced for artificial illumination according to the type of source (points A, B, and C in Fig. 5-14). As spectral colors of longer wavelength suffer extinction, the intersection point moves to the uncalibrated side of the triangle, the so-called purple line. It represents the purple tones that are not spectral colors themselves but a mixture of red and violet. (See color insert for Fig. 5-14.)

The characteristic color sequence during gas contrasting can be read off from the color chart. If the layer begins to form, the short wave colors interfere. Thus, the color sequence begins with yellow and traverses the colors shown on the color ring as they appear during gas contrasting. It must be taken into account that certain large layer thicknesses satisfy the condition for the destructive interference of certain colors but simultaneously satisfy the condition for the constructive interference of others, as follows:

\[
d = \frac{(m + 1)\lambda}{2\sqrt{n_s^2 - \sin^2 \phi}}
\]  

or for normal incidence,

\[
d = \frac{(m + 1)\lambda}{2n_s}
\]

where \( m = 0, 1, 2, 3, \ldots \). These colors make a reinforced contribution to the mixed color. When the layer thickness is considerably greater than the wave-length, the interference condition can be satisfied for several wavelengths simultaneously with the result that, as the color sequence is repeated over and over again, the colors in the sequence become modified. When the layer thickness is finally so great that light of all colors suffers extinction or reinforcement, the coloration fades because the total reflected light combines to colorless. The different phases then appear correspondingly colorless.

**SUMMARY**

The contrast between various constituents of multiphase materials is the most important factor for quantitative microstructural analysis. How to achieve it by gas contrasting is the subject of the present chapter, which starts with the description of the gas-contrasting chambers and
the technique of gas contrasting, continues with the demonstration and explanation of gas-contrast metal, composite, and ceramic microstructures, and finishes with the interpretation of the gas-contrasting effect on the basis of the theory of thin interference layers.

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REFERENCES

Fig. 5-3. Gas-contrasting chamber on microscopic cross stage (in action).

Fig. 5-6. Gas-contrasted Cu–W infiltration alloy (for example: Cu = violet, W = orange; oxide = blue)

Fig. 5-7. Gas-contrasted U₃Si₂–U₃Si intermetallic two-phase material: U₃Si is the matrix phase and U₃Si₂ is the included phase (oxygen as contrasting gas; steel cathode; 1.05kV).
Fig. 5-8. Gas-contrasted HfC-Co hard metal (HfC = brown; Co matrix phase = gold).

Fig. 5-9. Color sequence in HfC-Co hard metal by gas contrasting (oxygen as contrasting gas; steel cathode; 1.05kV).

Fig. 5-9. Color sequence in HfC-Co hard metal by gas contrasting (oxygen as contrasting gas; steel cathode; 1.05kV).
Fig. 5-10. Gas-contrasted porous iron-glass microstructures: pores, black; glass, grey; iron, white when unetched (oxygen as contrasting gas; steel cathode; 0.9 KV).

Figure 5-11. Gas-contrasted porous Al$_2$O$_3$-ceramic (carbon dioxide as contrasting gas; steel cathode; 1.5kV)
Fig. 5-12. White-light reflection on different phases, $\alpha$ and $\beta$: (a) without and (b) with layers of constant, and (c) with different thicknesses.

Fig. 5-14. Simplified color chart after Maxwell-Newton-Ostwald (numbers in nm).
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Untersuchungen zum Aufbau von interferenzfähigen Deckschichten auf gaskontrastiertem HfC-Co-Hartmetall

Investigations about the Structure of Interference Coatings on Gas-Contrasted HfC-Co Hard Metal

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Prof. Dr. rer. nat. Dr. h. c. Dr.-Ing. E. h. Günter Petzow zum 60. Geburtstag gewidmet.
Dedicated to Prof. Günter Petzow on the occasion of his 60th birthday

Einleitung

Gaskontrastierung
Die zu untersuchenden Proben enthielten Hafniumcarbid als Hartstoffphase und Kobalt als Bindefase. Sie wurden geschliffen, poliert und mit folgenden Bedingungen gaskontrastiert:

<table>
<thead>
<tr>
<th>Apparatur: Gasätzkammer 3</th>
<th>Equipment: Gas etching chamber 3</th>
</tr>
</thead>
<tbody>
<tr>
<td>Gas: Sauerstoff, ~ Atmosphärendruck</td>
<td>Gas: Oxygen, ~ atmospheric pressure</td>
</tr>
<tr>
<td>Kathoden: Blei, Stahl, Platin</td>
<td>Cathodes: Lead, Steel, Platinum</td>
</tr>
<tr>
<td>Temperatur: ~ 300 K</td>
<td>Temperature: ~ 300 K</td>
</tr>
<tr>
<td>Kontrastierdauer: 10 min</td>
<td>Contrasting period: 10 min</td>
</tr>
<tr>
<td>Spannung: 1,05 kV</td>
<td>Voltage: 1,05 kV</td>
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</tbody>
</table>

Introduction
In order to differentiate between the various components in a multiphase microstructure, the interaction between the surface of these components and light waves must produce adequate contrast. This is not usually the case with polished surfaces. Their special treatment for developing contrast or for increasing existing contrast is therefore an important part of the preparation in quantitative micro-structural analysis 1) 2). Gas contrasting is a successful contrasting technique, particularly for multiphase materials 3) 4). It has been used here for the preparation of an HfC-Co hard metal microstructure, the surface coatings of which were subsequently investigated by auger electron spectroscopy.

Gas Contrasting
The specimens under investigation contained hafnium carbide as the hard phase and cobalt as the binding phase. They were ground, polished and gas-contrasted under the following conditions:

Apparatur: Gasätzkammer 3
Gas: Sauerstoff, ~ Atmosphärendruck
Kathoden: Blei, Stahl, Platin
Temperatur: ~ 300 K
Kontrastierdauer: 10 min
Spannung: 1,05 kV

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Figur 1 zeigt das gaskontrastierte Gefüge, in dem, bei Farbwiedergabe — unabhängig vom gewählten Kathodenmaterial — Kobalt gelb und Hafniumcarbid rot erscheint.

Schichtuntersuchung

Mit Hilfe der Auger-Elektronenspektroskopie wurden die Deckschichten auf den beiden Phasen separat untersucht. Um unterschiedlich tiefe Lagen der Schichten zu erfassen, wurden diese stufenweise mit Ar-Ionen abgesputtert. Die Versuchsbedingungen wurden bei allen Proben annähernd konstant gehalten:

Spannung \( E_p = 3000 \, \text{V} \)
Stromstärke \( I_p = 40 \, \mu \text{A} \)
Modulationsamplitude \( V_{\text{Mod}} = 2 \, \text{eV} \)
Verstärkerspannung \( V_{\text{Mult}} = 1500 \, \text{V} \)
Zeitkonstante \( RC = 30 \, \text{ms} \)
Empfindlichkeit \( \text{Sens} = 2 \, \text{mV} \)

Zum Vergleich wurde auch die stoffliche Zusammensetzung der unbeschichteten Oberfläche aufgenommen (Fig. 2), wobei zunächst eine dünnere Schicht \( \sim 2 \cdot 10^{-8} \, \text{m} \) abgesputtert und untersucht, danach wieder abgesputtert \( \sim 10^{-7} \, \text{m} \) und nochmals untersucht wurde.

In beiden Fällen konnten hauptsächlich die Elemente der Phasen nachgewiesen werden, also Hafnium und Kohlenstoff beim Hartstoff und Kobalt bei der Bindefase.

Investigation of Coating

The coatings on two phases were separately investigated using auger-electron spectroscopy. In order to detect the location of the coatings at different depths they were sputtered off step by step using argon ions. The experimental conditions were maintained approx. constant for all specimens:

Voltage \( E_p = 3000 \, \text{V} \)
Current intensity \( I_p = 40 \, \mu \text{A} \)
Modulation amplitude \( V_{\text{Mod}} = 2 \, \text{eV} \)
Amplifier voltage \( V_{\text{Mult}} = 1500 \, \text{V} \)
Time constant \( RC = 30 \, \text{ms} \)
Sensitivity \( \text{Sens} = 2 \, \text{mV} \)

For comparison the material composition of the uncoated surface was also recorded (fig. 2). In doing so, a thin coating \( \sim 2 \cdot 10^{-6} \, \text{m} \) was sputtered off and investigated, then sputtered off again \( \sim 10^{-5} \, \text{m} \) and reinvestigated.

In both cases the main elements of the phases were detected, i.e. hafnium and carbon in the case of the carbide phase and cobalt in the case of the binding phase.

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Die Ergebnisse der Auger-Analyse der mit Bleikathode kontrastierten Probe zeigt Fig. 3, diejenigen der mit Stahl- bzw. Platinkathoden kontrastierten Proben sind in Fig. 4 und 5 wiedergegeben.

Zusammenfassend stellt Fig. 6 graphisch dar, daß

- auf der HfC-Phase durch Anlagerung von Sauerstoff und Elementen des Kathodenmaterials an die Oberfläche eine stofflich nicht homogen zusammengesetzte, interferenzfähige Schicht aufwächst, an der die Elemente des Grundmaterials (Hf, C) nicht beteiligt sind.

- auf der Co-Phase durch Anlagerung von Sauerstoff und Elementen des Kathodenmaterials an die Oberfläche ebenfalls eine Schicht aufwächst, an deren Aufbau im Gegensatz zu den Verhältnissen auf der HfC-Phase Kobalt beteiligt ist.

Fig. 3. Auger-Diagramme der beschichteten HfC- (links) und Co-Phase (rechts) nach unterschiedlicher Abtragung der Oberfläche durch Sputtern (Beschichtung mit Blei-Kathode)

Fig. 3. Auger diagrams of coated HfC- (left) and Co-phase (right) after different degrees of surface removal sputtering (coating with lead cathode)

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The auger analysis results of the specimen which had been contrasted with the lead cathode are shown in fig. 3; figs. 4 and 5 depict those results obtained for specimens contrasted with steel and platinum cathodes.

Fig. 6 summarizes in graphic form that

- a materially inhomogenously composed interference coating develops on the Hf phase as a result of oxygen and elements comprising the cathode material being deposited on the surface and that the base material elements (Hf and C) are not present in the coating;

- a coating is likewise formed on the Co phase as a result of oxygen and cathode material elements being deposited on the surface, the ray-structure of which, in contrast to the conditions on the HfC phase, includes cobalt.
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Fig. 4. Auger-Diagramme der beschichteten HfC- (links) und Co-Phase (rechts) nach unterschiedlicher Abtragung der Oberfläche durch Sputtern (Beschichtung mit Stahl-Kathode).

Fig. 4. Auger diagrams of coated HfC- (left) and Co-phase (right) after different degrees of surface removal by sputtering (coating with steel cathode).

Fig. 5. Auger-Diagramme der beschichteten HfC- (links) und Co-Phase (rechts) nach unterschiedlicher Abtragung der Oberfläche durch Sputtern (Beschichtung durch Platin-Kathode).

Fig. 5. Auger diagrams of coated HfC- (left) and Co-phase (right) after different degrees of surface removal by sputtering (coating with platinum cathode).

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Die beim Kontrastieren entstehende Schicht besteht demnach aus einer aufgewachsenen Schicht und — möglicherweise — einer Übergangszone geringer Dicke und ist auf jeder der beiden Phasen insgesamt wie auch hinsichtlich dieser Zonen inhomogen und auf den beiden Phasen unterschiedlich stofflich zusammengesetzt.

Ähnliche Ergebnisse wurden bei Untersuchungen von Deckschichten erhalten, die sich bei chemischer Ätzung bilden.

In Fig. 2 bis 5 sind Näherungstiefen für die untersuchten Schichtlagen angegeben, die sich nicht auf Messungen am Probematerial selbst beziehen. Vielmehr wurde bei den Sputterversuchen eine Stahlprobe als Standard mitgeführt, an der unter gleichen Bedingungen die angegebenen Schichtlagen bzw. die Abtragsrate bestimmt wurden.

In der Literatur sind für rostfreien Stahl, Glas und Aluminium Sputterraten angegeben (2 keV; Ar⁺-Ionenstromdichte 150 µA/cm²; Sputterrate 7–13 nm/min), deren Übertragung auf die geometrischen Verhältnisse des vorliegenden Falles die Extrapolation der Sputterrate erlaubt (2 keV; Ar⁺-Ionenstromdichte 150 µA/cm²; Sputterrate 7–13 nm/min), welche mit der Probenart und -größe zusammenhängen.

Fig. 6. Qualitative Veranschaulichung der Zusammensetzung der beschichteten HfC- (oben) und Co-Phase (unten)

Fig. 6. Qualitative illustration of the composition coated HfC- (top) and Co-phase surface (bottom)

The coating formed during contrasting thus consists of a developed coating and, possibly, a transition zone of negligible thickness is with respect to these zones inhomogeneously formed overall and has a different material composition on the two phases.

Similar results were obtained from investigations on coatings which form during chemical etching.

Approximate depths are given in figs. 2 to 5 for the coatings under investigations which do not themselves relate to measurements on the specimen material. On the contrary, a steel specimen was used as a standard in the sputter experiments on which the coatings mentioned and the removal rate were determined under identical conditions.

Sputter rates for stainless steel, glass and aluminium are given in the literature (2 keV; Ar⁺-ion current density 150 µA/cm²; sputter rate 7–13 nm/min), which can be transferred to the geometric conditions of the present case and permit the extrapolation of the sputter rate.
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Emissionsstrom 30 mA; Argondruck $7 \cdot 10^{-4}$ bar; Spürrate $\sim 5$ nm/min).

Um zu überprüfen, ob dieser Richtwert größenordnungsmäßig stimmt, wurde versucht, aus dem durch den Abtrag entstandenen Gewichtsverlust unter Zugrundelegung des mittleren Durchmessers des sichtbaren Sputterflecks und der Dichte des Materials, die Abtragstiefe zu berechnen. Es ergaben sich beispielsweise folgende Vergleichswerte:

<table>
<thead>
<tr>
<th>Stahl/Steel 14301</th>
<th>2,2 $\mu$m</th>
</tr>
</thead>
<tbody>
<tr>
<td>Stahl/Steel 14988</td>
<td>4,45 $\mu$m</td>
</tr>
<tr>
<td>Steellit (Co-Basis)</td>
<td>2,2 $\mu$m</td>
</tr>
<tr>
<td>Steellit (Co-based)</td>
<td>2,2 $\mu$m</td>
</tr>
</tbody>
</table>

Da die Dicke der zu untersuchenden Schichten auf die Proben um mindestens eine Größenordnung geringer war ($< 100$ nm) als diejenige für die Vergleichswerte, wurden zusätzlich Schichten bekannter Dicke von Al (60 nm) bzw. Ti (240 nm) auf Glas durch Ar-Ionen abgetragen und die bis zum Erreichen der Glasmatrix erforderlichen Zeiten registriert. Die in der Literatur angegebenen Abtragsraten für Al und Ti wurden bestätigt: Al hat eine ähnliche Abtragsrate wie rostfreier Stahl, die Abtragsrate von Ti ist etwa halb so groß.

Die in Fig. 2 bis 5 angegebenen Schichtlagentiefen beziehen sich ausschließlich auf diese Stahlbzw. Al-Standards. Eine direkte Angabe zur Schicht- und Schichtlagendicke auf der HfC-bzw. Co-Phase erlauben sie nicht.

Zusammenfassung

Das Gefüge eines HfC-Co-Hartmetalls wurde zur quantitativen Gefügeanalyse gaskontrastiert. Dabei bilden sich auf den Gefügebestandteilen interferenzfähige Schichten. Sie verursachen den gewünschten Farbkontrast. Ihr Aufbau wurde in der vorliegenden Arbeit mittels Auger-Elektronenspektroskopie untersucht. Es wurde gefunden, daß unabhängig vom benutzten Kathodenmaterial die Schicht insgesamt hauptsächlich Sauerstoff und das Kathodenmaterial enthält, daß die Sauerstoffkonzentration ab einer gewissen Tiefe in der Schicht etwa den Wert der unbeschichteten Probe annimmt, daß unter-

keV; emission current 30 mA; argon pressure $7 \cdot 10^{-4}$ bar; sputter rate $\sim 5$ nm/min).

To check whether this approximate value is of the correct magnitude an attempt was made to calculate the removal depth from the weight loss caused by removal using as a basis the mean diameter of the visible sputter speck and the material density. The following comparative values were obtained by way of example:

<table>
<thead>
<tr>
<th>Stahl/Steel 14301</th>
<th>2,2 $\mu$m</th>
</tr>
</thead>
<tbody>
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<td>2,2 $\mu$m</td>
</tr>
</tbody>
</table>

As the thickness of the coatings to be investigated was at least a size smaller ($< 100$ nm) on the specimens than those for the comparative values, coatings of known thickness of Al (60 nm) and Ti (240 nm) on glass were also removed by Ar ions and the times required to the point of obtaining the glass matrix were recorded. The removal rates for Al and Ti given in the literature were confirmed: Al has a removal rate similar to stainless steel and the removal rate of Ti is about half that.

The coating layer depths given in figs. 2 to 5 refer solely to these steel and Al standards. They do not permit a direct statement on the coating thickness and coating layer thickness on the HfC and Co phase.

Summary

The structure of an HfC-Co hard metal was gas-contrastated for the purpose of quantitative microstructural analysis. Interference coatings were formed on the structural components in the process. These produce the desired colour contrast. Their structure is investigated in this work using auger electron spectroscopy. It was found that, independent of the cathode material used, the coating overall contains mainly oxygen and the cathode element, that the oxygen concentration beyond a certain depth in the coating assumes approximately the value of uncoated specimen, that below this depth in the coating
halb dieser Tiefe in der Schicht das Kathodenmaterial nicht mehr nachgewiesen werden kann und daß oberhalb dieser Tiefe in der Schicht auf der HfC-Phase kein Hafnium oder Kohlenstoff nachweisbar ist, während auf der Co-Phase Kobalt am Schichtaufbau beteiligt ist.

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Translation: Dr. Castle

Familie Champignon auf dem Sonntagsausflug!
A Mushroom Family on the Way to Their Sunday Picknick
Metalltropfen auf einer Sinterkeramik, ungeätzt. 200×
Metal droplets on sintered ceramic, unetched. 200×
Aufnahme/micrograph: Erika Bayer, BAYER AG, Krefeld-Uerdingen

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